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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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N-Channel Logic Level Power MOSFET 60 V, 16 A, 47 mΩ

These are N-Channel power MOSFETs manufactured using a modern process. This process, which uses feature sizes approaching those of LSI integrated circuits gives optimum utilization of silicon, resulting in outstanding performance. They were designed for use in applications such as switching regulators, switching converters, motor drivers, relay drivers and emitter switches for bipolar transistors. This performance is accomplished through a special gate oxide design which provides full rated conductance at gate bias in the 3V to 5V range, thereby facilitating true on-off power control directly from logic level (5V) integrated circuits.

Formerly developmental type TA49027.

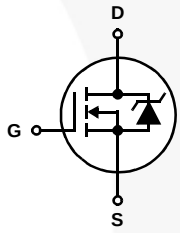
Features

- 16A, 60V
- $r_{DS(ON)} = 0.047\Omega$
- Temperature Compensating PSPICE® Model
- Can be Driven Directly from CMOS, NMOS, TTL Circuits
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Related Literature
  - TB334 “Guidelines for Soldering Surface Mount Components to PC Boards”

Ordering Information

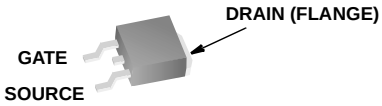
PART NUMBER	PACKAGE	BRAND
RFD16N06LESM9A	TO-252AA	16N06LE

Symbol



Packaging

JEDEC TO-252AA



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Absolute Maximum Ratings $T_C = 25^oC$, Unless Otherwise Specified

		RFD16N06LESM	UNITS
Drain to Source Voltage (Note 1)	V_{DSS}	60	V
Drain to Gate Voltage (R_{GS} = 20kΩ) (Note 1)	V_{DGR}	60	V
Gate to Source Voltage	V_{GS}	+10, -8	V
Continuous Drain Current	I_D	16	A
Pulsed Drain Current (Note 3)	I_{DM}	Refer to Peak Current Curve	
Pulsed Avalanche Rating	E_{AS}	Refer to UIS Curve	
Power Dissipation	P_D	90	W
Derate Above 25^oC		0.606	$W/^oC$
Operating and Storage Temperature	T_J, T_{STG}	-55 to 175	^oC
Maximum Temperature for Soldering			
Leads at 0.063in (1.6mm) from Case for 10s	T_L	300	^oC
Package Body for 10s, See Techbrief 334	T_{pkg}	260	^oC

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^oC$ to 150^oC.

Electrical Specifications $T_C = 25^oC$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNITS
Drain to Source Breakdown Voltage	BV_{DSS}	I_D = 250μA, V_{GS} = 0V, Figure 11		60	-	-	V
Gate Threshold Voltage	$V_{GS(TH)}$	V_{GS} = V_{DS}, I_D = 250μA, Figure 10		1	-	3	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 55V, V_{GS} = 0V		-	-	1	μA
		V_{DS} = 50V, V_{GS} = 0V, $T_C = 150^oC$		-	-	250	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS} = +10, -8V		-	-	10	μA
Drain to Source On Resistance (Note 2)	$r_{DS(ON)}$	I_D = 16A, V_{GS} = 5V		-	-	0.047	Ω
Turn-On Time	t_{ON}	V_{DD} = 30V, I_D = 16A, R_L = 1.88Ω, V_{GS} = 5V, R_{GS} = 5Ω Figures 16, 17		-	-	100	ns
Turn-On Delay Time	$t_{d(ON)}$			-	11	-	ns
Rise Time	t_r			-	60	-	ns
Turn-Off Delay Time	$t_{d(OFF)}$			-	48	-	ns
Fall Time	t_f			-	35	-	ns
Turn-Off Time	t_{OFF}			-	-	115	ns
Total Gate Charge	$Q_{g(TOT)}$	V_{GS} = 0V to 10V	V_{DD} = 48V, I_D = 16A, R_L = 3Ω Figures 18, 19	-	51	62	nC
Gate Charge at 5V	$Q_{g(5)}$	V_{GS} = 0V to 5V		-	29	35	nC
Threshold Gate Charge	$Q_{g(TH)}$	V_{GS} = 0V to 1V		-	1.8	2.6	nC
Input Capacitance	C_{ISS}	V_{DS} = 25V, V_{GS} = 0V, f = 1MHz Figure 12		-	1350	-	pF
Output Capacitance	C_{OSS}			-	300	-	pF
Reverse Transfer Capacitance	C_{RSS}			-	90	-	pF
Thermal Resistance Junction to Case	$R_{\theta JC}$			-	-	1.65	$^oC/W$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	TO-252AA		-	-	80	$^oC/W$

Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Source to Drain Diode Voltage (Note 2)	V_{SD}	I_{SD} = 16A	-	-	1.5	V
Diode Reverse Recovery Time	t_{rr}	I_{SD} = 16A, dI_{SD}/dt = 100A/μs	-	-	125	ns

NOTES:

2. Pulse Test: Pulse Width ≤300μs, Duty Cycle ≤2%.
3. Repetitive Rating: Pulse Width limited by max junction temperature.

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Typical Performance Curves Unless Otherwise Specified

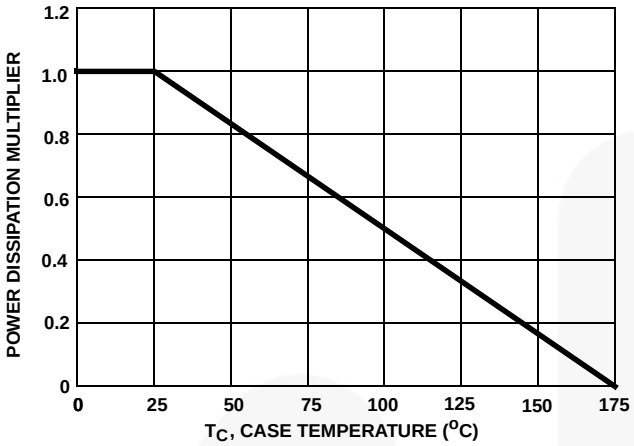


FIGURE 1. NORMALIZED POWER DISSIPATION vs CASE TEMPERATURE

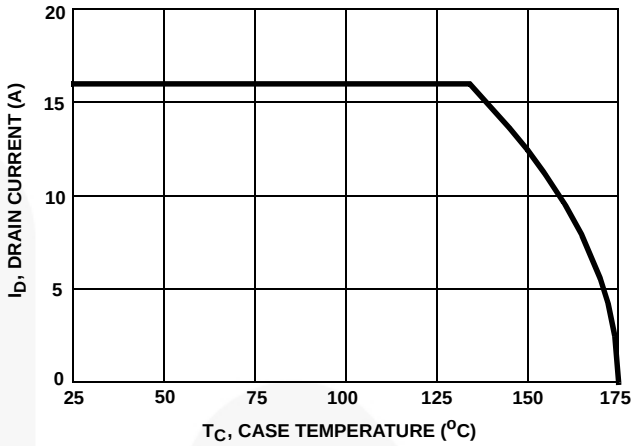


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs CASE TEMPERATURE

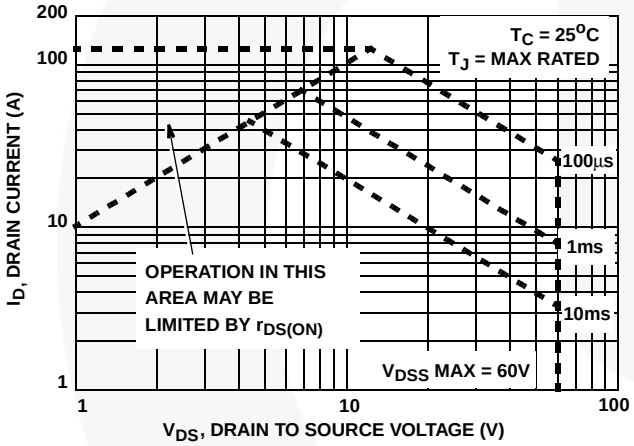


FIGURE 3. FORWARD BIAS SAFE OPERATING AREA

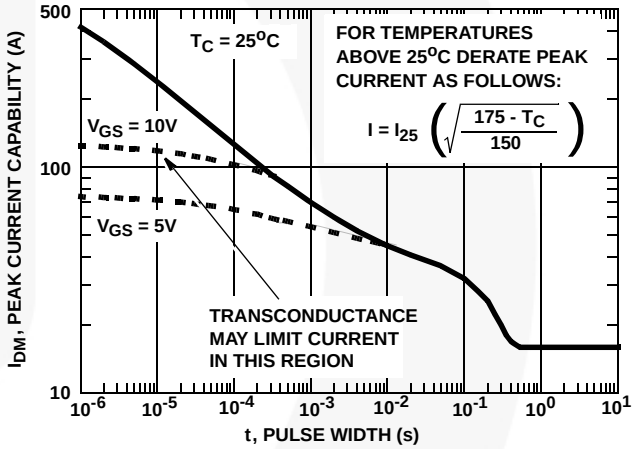


FIGURE 4. PEAK CURRENT CAPABILITY

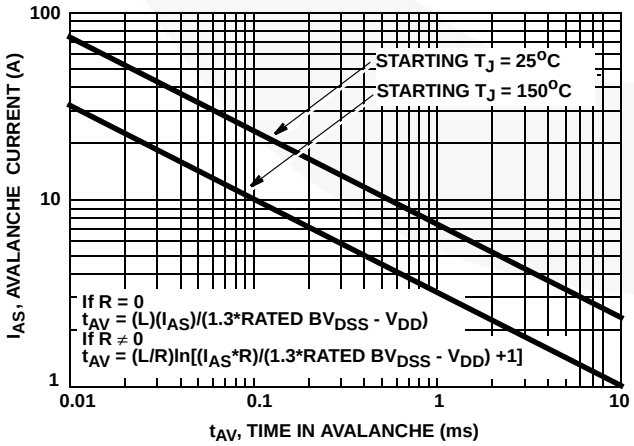


FIGURE 5. UNCLAMPED INDUCTIVE SWITCHING

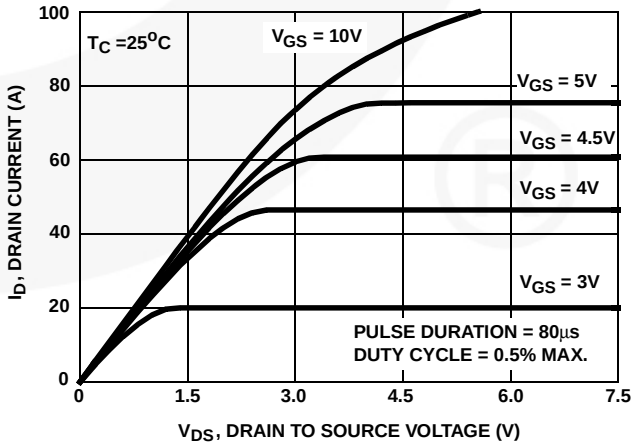


FIGURE 6. SATURATION CHARACTERISTICS

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Typical Performance Curves Unless Otherwise Specified **(Continued)**

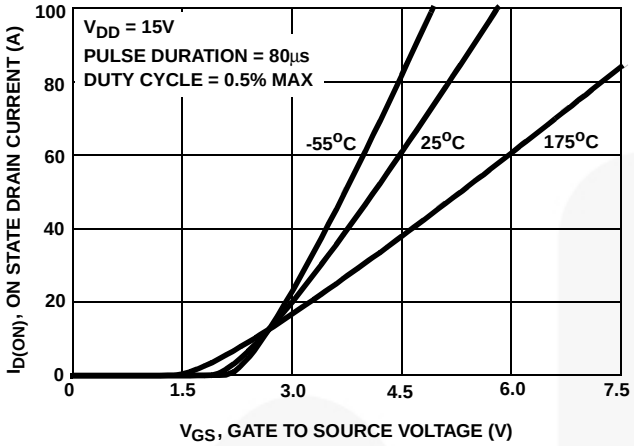


FIGURE 7. TRANSFER CHARACTERISTICS

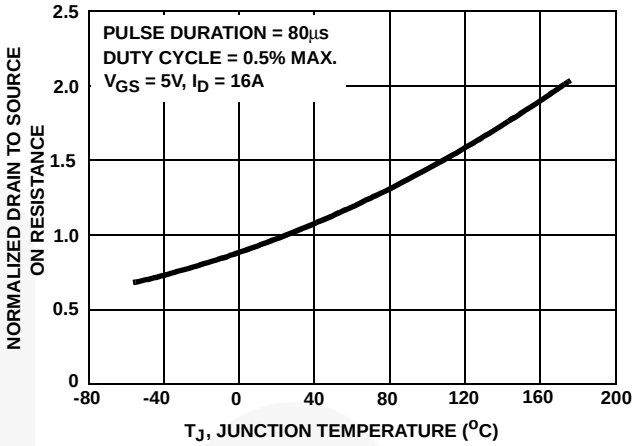


FIGURE 8. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

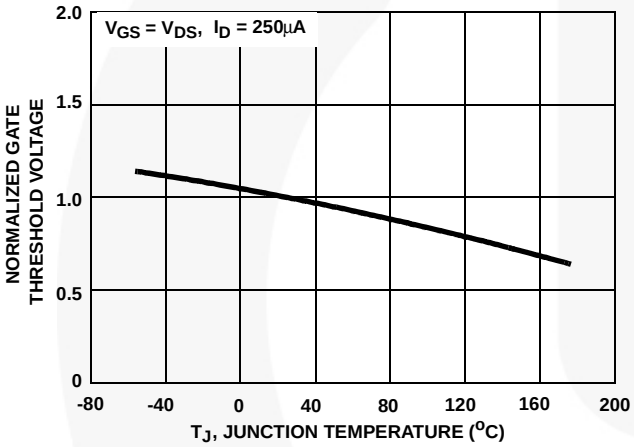


FIGURE 9. NORMALIZED GATE THRESHOLD VOLTAGE vs TEMPERATURE

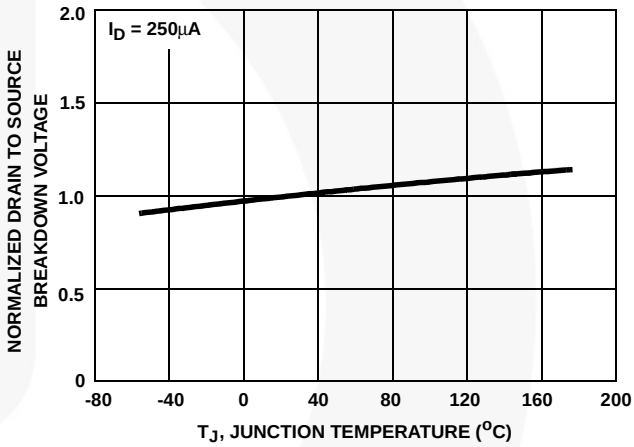


FIGURE 10. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE

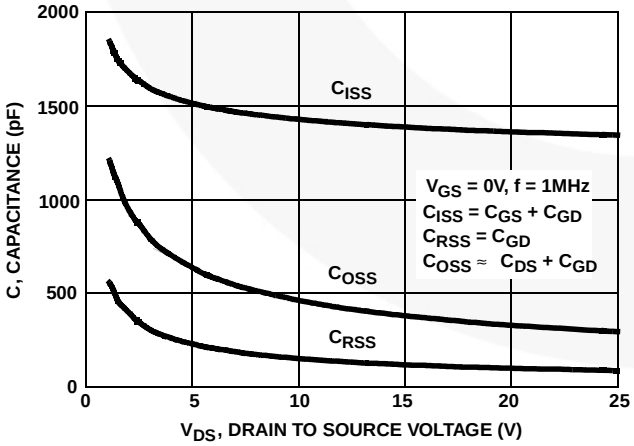
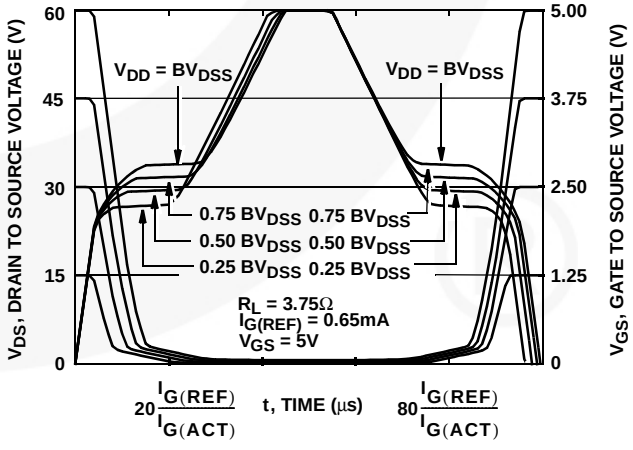


FIGURE 11. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260.

FIGURE 12. NORMALIZED SWITCHING WAVEFORMS FOR CONSTANT GATE CURRENT

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Test Circuits and Waveforms

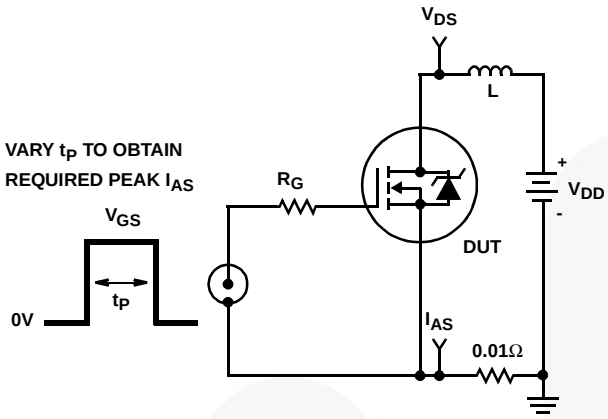


FIGURE 13. UNCLAMPED ENERGY TEST CIRCUIT

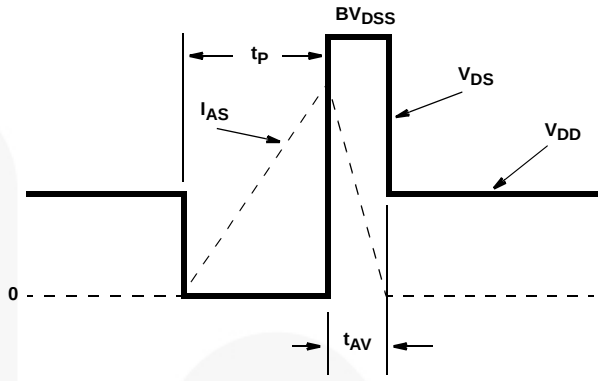


FIGURE 14. UNCLAMPED ENERGY WAVEFORMS

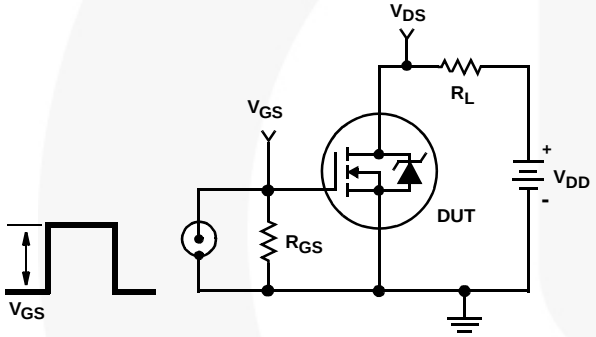


FIGURE 15. SWITCHING TIME TEST CIRCUIT

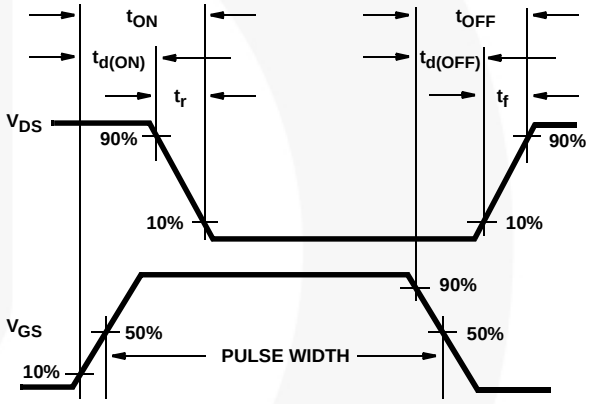


FIGURE 16. RESISTIVE SWITCHING WAVEFORMS

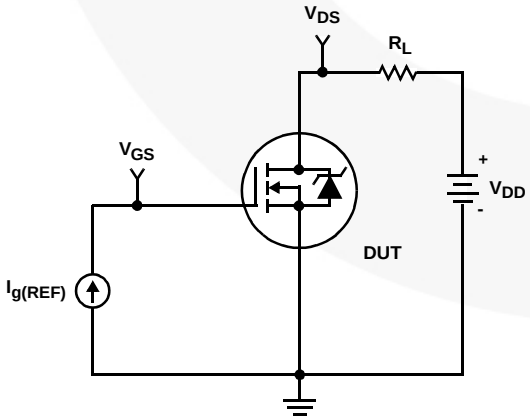


FIGURE 17. GATE CHARGE TEST CIRCUIT

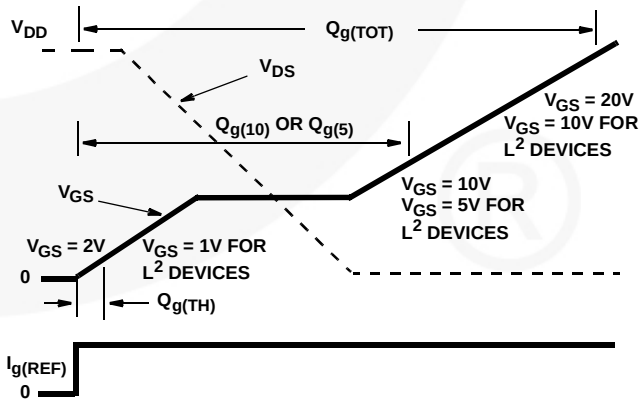


FIGURE 18. GATE CHARGE WAVEFORMS

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PSPICE Electrical Model

SUBCKT RFD16N06LESM 2 1 3 ; rev 8/2/93

```
CA 12 8 1.46e-9
CB 15 14 1.46e-9
CIN 6 8 1.0e-9

DBODY 7 5 DBODYMOD
DBREAK 5 11 DBREAKMOD
DPLCAP 10 5 DPLCAPMOD

EBREAK 11 7 17 18 66.0
EDS 14 8 5 8 1
EGS 13 8 6 8 1
ESG 6 10 6 8 1
EVTHRES 6 21 19 8 1
EVTEMP 20 6 18 22 1

IT 8 17 1

LDRAIN 2 5 1e-9
LGATE 1 9 5.5e-9
LSOURCE 3 7 4.4e-9

MMED 16 6 8 8 MMEDMOD
MSTRO 16 6 8 8 MSTROMOD
MWEAK 16 21 8 8 MWEAKMOD

RBREAK 17 18 RBREAKMOD 1
RDRAIN 50 16 RDRAINMOD 7.0e-3
RGATE 9 20 3.6
RLDRAIN 2 5 10
RLGATE 1 9 55
RLSOURCE 3 7 44
RSLC1 5 51 RSLCMOD 1e-6
RSLC2 5 50 1e3
RSOURCE 8 7 RSOURCEMOD 1.45e-2
RVTHRES 22 8 RVTHRESMOD 1
RVTEMP 18 19 RVTEMPMOD 1

S1A 6 12 13 8 S1AMOD
S1B 13 12 13 8 S1BMOD
S2A 6 15 14 13 S2AMOD
S2B 13 15 14 13 S2BMOD

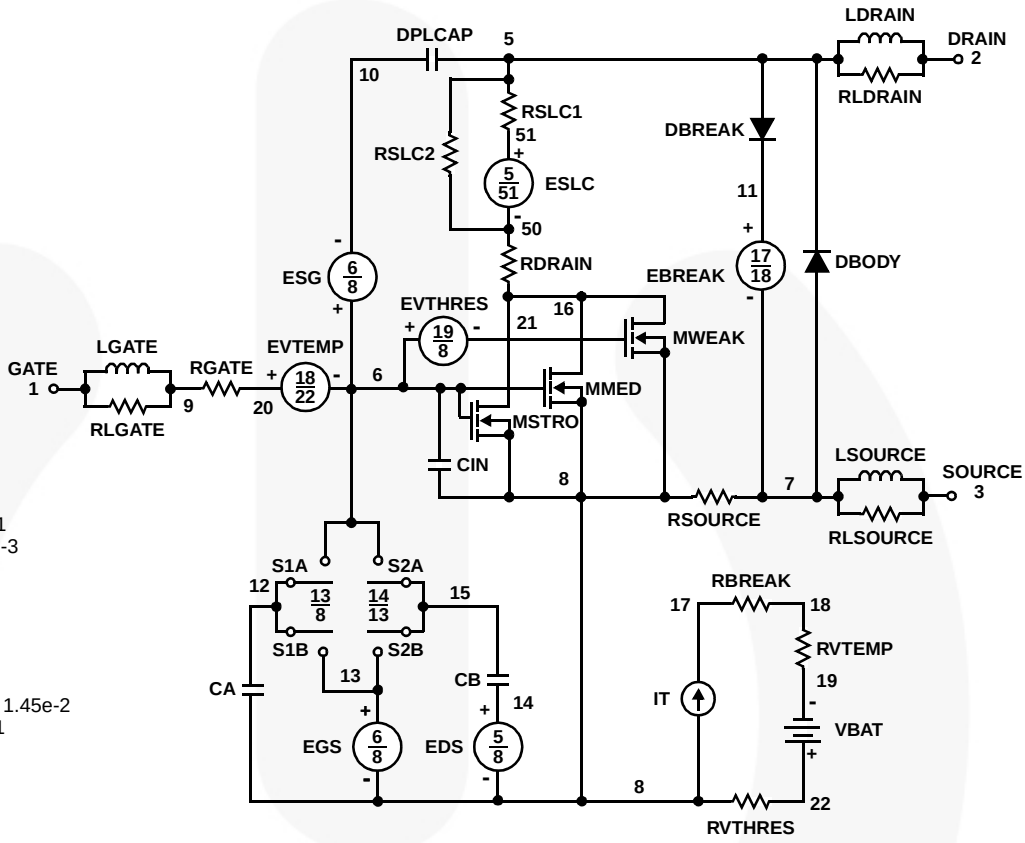
VBAT 22 19 DC 1

ESLC 51 50 VALUE={(V(5,51)/ABS(V(5,51)))*(PWR(V(5,51)/(1e-6*100),3.5))}

.MODEL DBODYMOD D (IS = 6.3e-13 RS = 6.8e-3 TRS1 = 1e-3 TRS2 = 1e-6 XTI = 4.3 CJO = 1.28e-9 TT = 5.1e-8 M = 0.5)
.MODEL DBREAKMOD D (RS = 2.9e-1 TRS1 = 1e-4 TRS2 = 0)
.MODEL DPLCAPMOD D (CJO = 9.5e-10 IS = 1e-30 N = 10 M = 0.82)
.MODEL MMEDMOD NMOS (VTO = 2.10 KP = 6 IS = 1e-30 N = 10 TOX = 1 L = 1u W = 1u RG = 3.6)
.MODEL MSTROMOD NMOS (VTO = 2.45 KP = 60.5 IS = 1e-30 N = 10 TOX = 1 L = 1u W = 1u)
.MODEL MWEAKMOD NMOS (VTO = 1.79 KP = 0.13 IS = 1e-30 N = 10 TOX = 1 L = 1u W = 1u RG = 36 RS = 0.1)
.MODEL RBREAKMOD RES (TC1 = 1.2e-3 TC2 = -5e-7)
.MODEL RDRAINMOD RES (TC1 = 1.3e-2 TC2 = 3.1e-5)
.MODEL RSLCMOD RES (TC1 = 5.5e-3 TC2 = 7e-6)
.MODEL RSOURCEMOD RES (TC1 = 1e-3 TC2 = 1e-6)
.MODEL RVTHRESMOD RES (TC1 = -1.8e-3 TC2 = -5.8e-6)
.MODEL RVTEMPMOD RES (TC1 = -1.7e-3 TC2 = 8e-7)

.MODEL S1AMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = -4.8 VOFF= -2.8)
.MODEL S1BMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = -2.8 VOFF= -4.8)
.MODEL S2AMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = -0.6 VOFF= 0.5)
.MODEL S2BMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = 0.5 VOFF= -0.6)

.ENDS
```



For further discussion of the PSPICE model, consult **A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options**; IEEE Power Electronics Specialist Conference Records, 1991, written by William J. Hepp and C. Frank Wheatley.

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SuperSOT™-6
SuperSOT™-8
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